

Energy relaxation and electron-phonon coupling in laser-excited metals

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■ **Motivation:** first-principles accurate determination of electron-phonon coupling factors for a wide variety of elements and materials are in high demand.

■ **Formula:**

$$G_{ep}(T_e, T_l, t) = \frac{2\pi N_c}{g[\mu(T_e)](T_e - T_l)} \int_{-\infty}^{\infty} g^2(\epsilon, T_e, T_l) \frac{\partial f(\epsilon, T_e)}{\partial \epsilon} d\epsilon \times \int_0^{\infty} (\hbar\omega)^2 \alpha^2 F(\omega, T_e, T_l, t) [n_B^e(\omega, T_e, t) - n_B^p(\omega, T_l, t)] d\omega.$$

■ **Scheme:** 1) finite temperature DFT + tetrahedron method (to calculate T_e -dependent electron density of states). 2) finite temperature DFPT (to get the T_e -dependent Eliashberg function, unshifted k-point grid featuring $32 \times 32 \times 32$ points and a subset thereof for the q-point grid of $8 \times 8 \times 8$).

Electron-phonon coupling factor for simple metal Aluminum

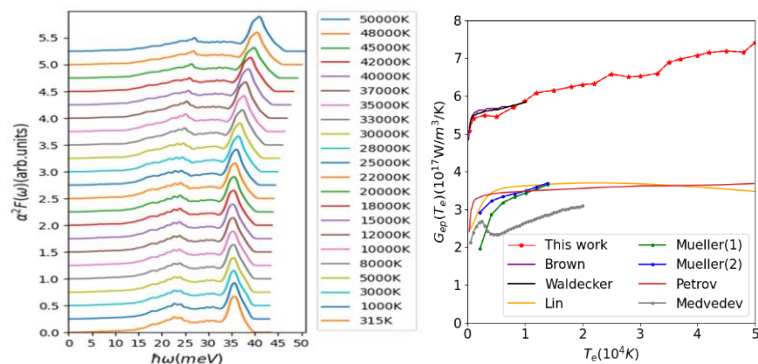


Fig.1: Eliashberg function of Al at different electron temperatures.

Fig.2: electron temperature-dependent electron-phonon coupling factor of Al.

Broadening and shifting of spectral weights.

Coupling strength of longitudinal mode alone around 3.

More complicated broadening and shifting behavior.

Little change with increasing electron temperature.

Longitudinal mode plays a dominant role.

Dramatic change under high electronic excitation.

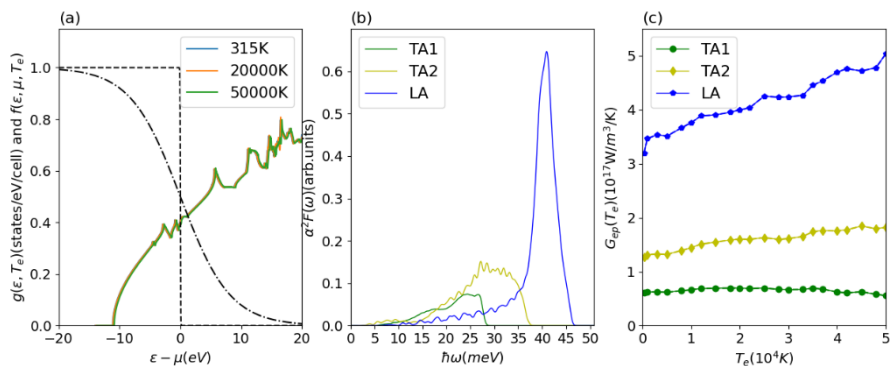


Fig.3.: (a) electronic DOS of Al for different electron temperatures and Fermi distribution functions. (b) Eliashberg function of Al for three partial branches (TA1, TA2, LA) at $T_e=50000K$ and (c) electron temperature-dependent partial electron-phonon coupling factor of Al (TA1, TA2, LA).

> we need the non-thermal lattice model, see Waldecker et al. PRX 2016.

Electron-phonon coupling factor for transition metal Copper

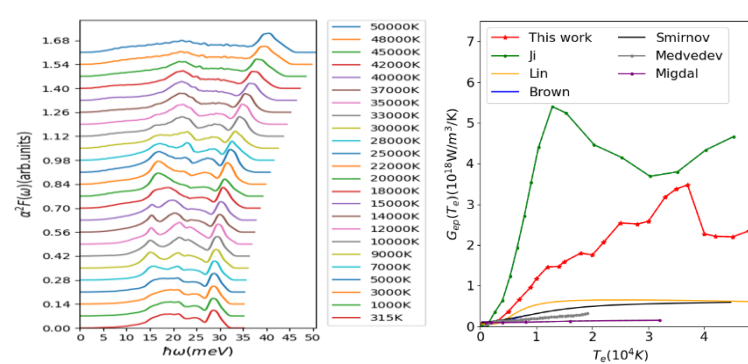


Fig.4: Eliashberg function of Cu at different electron temperatures.

Fig.5: electron temperature-dependent electron-phonon coupling factor of Cu.

A characteristic dip at 37000K.

No dominant partial mode.

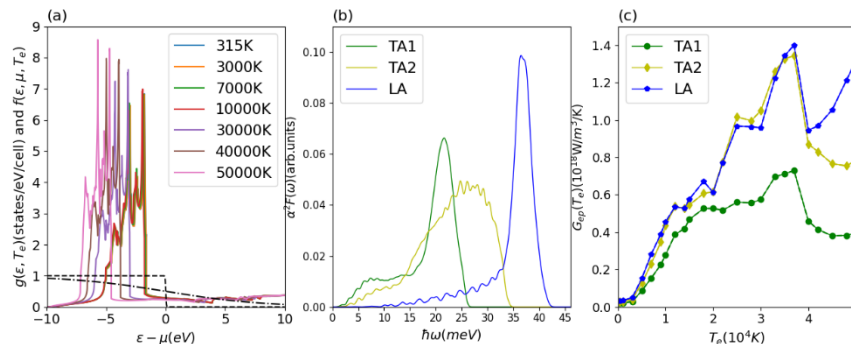


Fig.6.: (a) electronic DOS of Cu for different electron temperatures and Fermi distribution functions. (b) Eliashberg function of Cu for three partial branches (TA1, TA2, LA) at $T_e=40000K$ and (c) electron temperature-dependent partial electron-phonon coupling factor of Cu (TA1, TA2, LA).

> The two-temperature model should be valid (contrary to Al).